Stability in Metal Halide Perovskite Solar Cells – A Matter of Mixing



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Renewable Energy

https://youtu.be/iwNDPFi_mTM



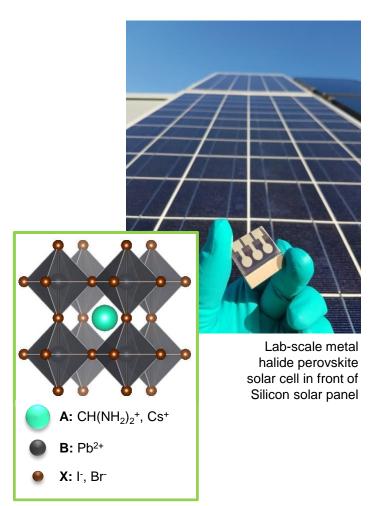
Introduction

Game changer in photovoltaic (PV) technology: Metal halide perovskite solar cells

- Materials based on crystal structure with ABX₃ formula
- High energy conversion efficiency through desirable optical and electrical properties
- Solution processing enables low-cost production

Goal: compete with Silicon PV for 30 year stability

- > Device performance degradation remains a challenge
- Mixing ions in crystal lattice helps stabilize structure

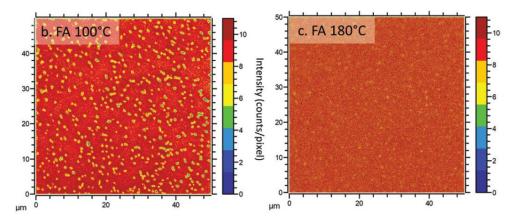




Objective

- > If we want to improve the **stability**, we need to understand the **failure mechanisms**
- Previous results¹ suggest:
- local heterogeneity depends on annealing temperature of perovskite thin film
- 2) local heterogeneity drives phase segregation and causes device failure

<u>Hypothesis:</u> Higher annealing temperatures promotes mixing, which prevents phase segregation and leads to improved stability



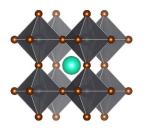
Time-of-Flight Secondary Ion Mass Spectroscopy (ToF SIMS) of perovskite films containing $CH(NH_2)_2^+$ (FA), Cs, Pb and I, annealed at 100°C (left) and 180°C (right), showing the local distribution of FA.¹



Methods – Samples

State-of-the-art perovskite solar cell with **mixed A-site**

 $\textbf{FA}_{0.83}\textbf{Cs}_{0.17}\textbf{Pbl}_3$

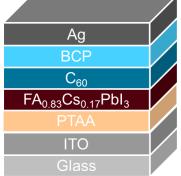


83% CH(NH₂)₂⁺ ("FA") 17% Cs⁺



low annealing temperature





Chose two annealing temperatures for the perovskite absorber



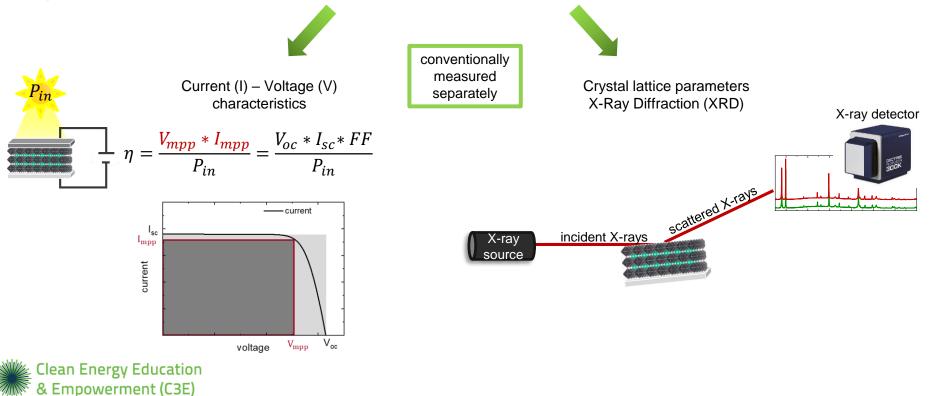
high annealing temperature





Methods – IV & XRD

Figures of merit: Photovoltaic performance (efficiency, η) and crystal structure



Methods – operando XRD

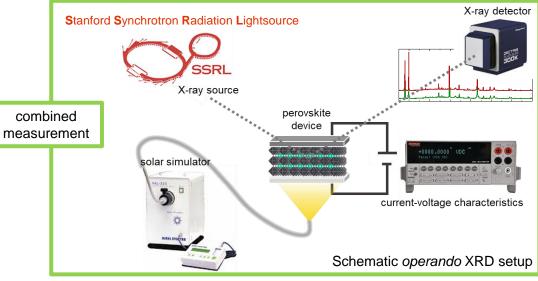
Synchrotron Radiation, high energy and flux enables:

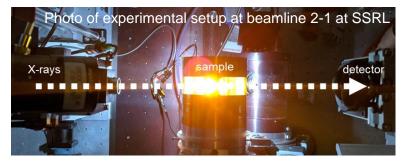
- Rapid data collection (short integration times)
- 2) Penetration of active layer through the top metal electrode

Operando XRD

In situ characterization of device efficiency and crystal structure under electrical load



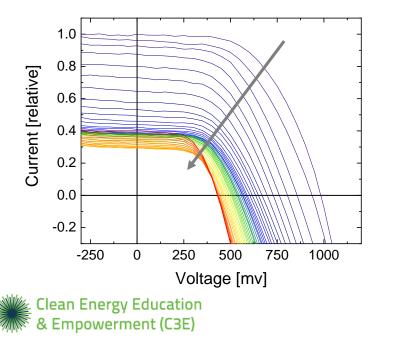




Results - in situ IV

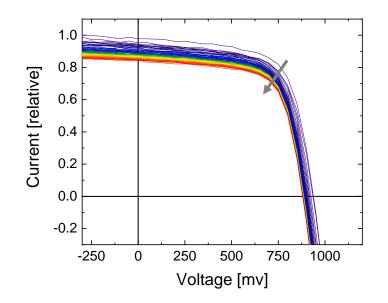
low annealing temperature

- > in situ IV over 11h shows loss in V_{oc} and I_{sc}
- severe device degradation



high annealing temperature

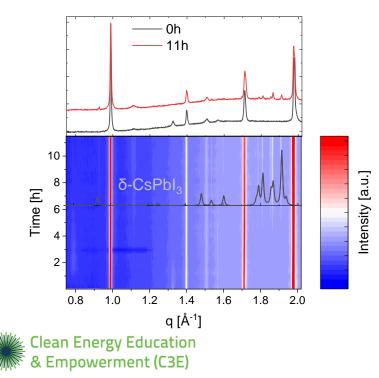
in situ IV over 19 h shows improved stability compared to lower annealed device



Results – operando XRD

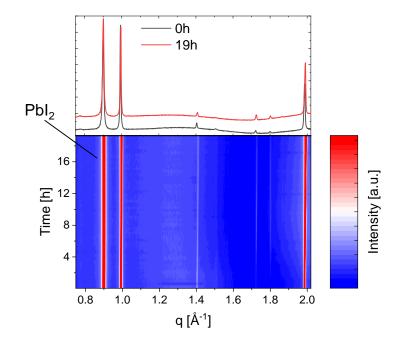
low annealing temperature

> secondary phase formation, δ -CsPbl₃



high annealing temperature

no structural changes observed



Conclusions

Confirmed hypothesis:

- Secondary phase formation for lower annealed device
- New phase identified as hexagonal δ -CsPbl₃, which is photo-inactive
- Lower-annealed device shows severe loss in V_{oc} and I_{sc} , resulting in lower efficiency η
- No structural changes and improved device stability for higher annealed sample



Future work- The thermodynamic limits of mixing

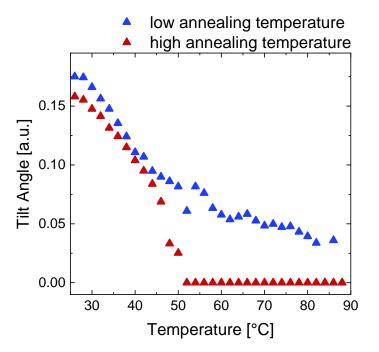
Previously probed heterogeneity length scales in micrometer range

Hypothesis:

Small length scale heterogeneities also have detrimental impact on structural stability

But how to probe if there is no secondary phase?

- Demonstrate manifestation of nanoscale heterogeneities in "smearing" of tetragonal to cubic phase transition
- Octahedral tilt angle as measure for "smearing" (tilt angle 0° = cubic lattice)





References

L. T. Schelhas, Z. Li, J. A. Christians, A. Goyal, P. Kairys, S. P. Harvey, D. H. Kim, K. H. Stone, J. M. Luther, K. Zhu, V. Stevanovic, J. J. Berry, *Energy Environ. Sci.* **2019**, *12*, 1341.



Acknowledgments













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